

#### 2STA1962

# High power PNP epitaxial planar bipolar transistor

Preliminary Data

#### **Features**

- High breakdown voltage V<sub>CEO</sub> > -230V
- Complementary to 2STC5242
- Fast-switching speed
- Typical f<sub>T</sub>= 30MHz

#### **Application**

Audio power amplifier

#### **Description**

This device is a PNP transistor manufactured using new BiT-LA (Bipolar Transistor for linear amplifier) technology. The resulting transistor shows good gain linearity behaviour.

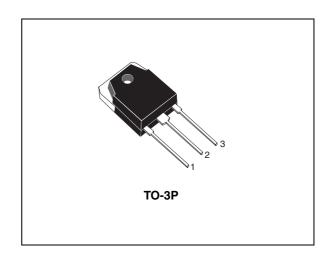


Figure 1. Internal schematic diagram

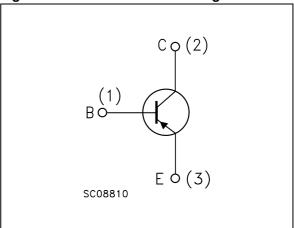


Table 1. Device summary

Order code	Marking	Package	Packaging
2STA1962	2STA1962	TO-3P	Tube

Electrical ratings 2STA1962

# 1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-base voltage (I <sub>E</sub> =0)	-230	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	-230	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	-5	V
I <sub>C</sub>	Collector current	-15	Α
I <sub>CM</sub>	Collector peak current	-30	Α
P <sub>tot</sub>	Total dissipation at T <sub>C</sub> = 25°C	130	W
T <sub>stg</sub>	Storage temperature	-55 to 150	°C
TJ	Operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJ-case</sub>	Thermal resistance junction-case Max	0.96	°C/W

## 2 Electrical characteristics

( $T_{CASE}$ =25°C unless otherwise specified)

Table 4. Electrical characteristics

Symbol	Parameter	Test co	nditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current (I <sub>E</sub> = 0)	V <sub>CB</sub> = -230V				-5	μΑ
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = -5V				-5	μΑ
V <sub>(BR)CEO</sub> <sup>(1)</sup>	Collector-emitter breakdown voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = -50mA		-230			V
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage (I <sub>E</sub> = 0)	$I_C = -100 \mu A$		-230			٧
V <sub>(BR)EBO</sub> <sup>(1)</sup>	Emitter-base breakdown voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = -1mA		-5			٧
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	I <sub>C</sub> = -8A;	I <sub>B</sub> = -800mA			-3	٧
$V_{BE}$	Base-emitter voltage	$I_C = -7A;$	$V_{CE} = -5V$			-1.5	V
h <sub>FE</sub>	DC current gain	$I_{C} = -1A;$ $I_{C} = -7A;$	$V_{CE} = -5V$ $V_{CE} = -5V$	80 35		160	
f <sub>T</sub>	Transition frequency	I <sub>C</sub> = -1A;	V <sub>CE</sub> = -5V		30		MHz
C <sub>CBO</sub>	Collector-base capacitance I <sub>E</sub> = 0	V <sub>CB</sub> = -10V;	f = 1MHz		225		pF

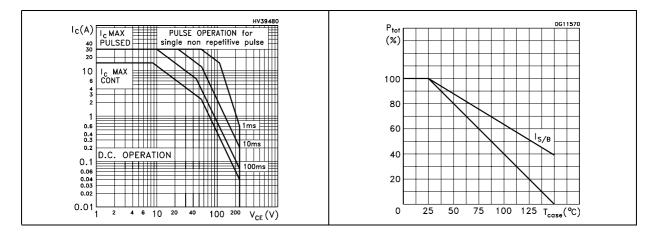
<sup>1.</sup> Pulsed: pulse duration =  $300\mu s$ , duty cycle  $\leq 1.5\%$ 

Electrical characteristics 2STA1962

## 2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating curve



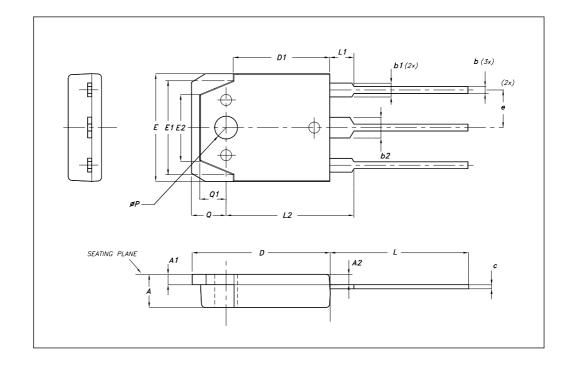
## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: <a href="https://www.st.com">www.st.com</a>

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TO-3P		

DIM		mm.	
DIM.	MIN.	TYP	MAX.
Α	4.6		5
A1	1.45	1.50	1.65
A2	1.20	1.40	1.60
b	0.80	1	1.20
b1	1.80		2.20
b2	2.80		3.20
С	0.55	0.60	0.75
D	19.70	19.90	20.10
D1		13.90	
E	15.40		15.80
E1		13.60	
E2		9.60	
е	5.15	5.45	5.75
L	19.50	20	20.50
L1		3.50	
L2	18.20	18.40	18.60
Р	3.10		3.30
Q		5	
Q1		3.80	



**577** 

2STA1962 Revision history

# 4 Revision history

Table 5. Document revision history

Date	Revision	Changes
28-Sep-2007	1	Initial release

Revision history 2STA1962

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